

YJ Planar Schottky Barrier Diode Die Specification

150V 30A, 122mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB122H150AS-280A

Main Products Characteristics

Maximum Ratings

Static Electrical Characteristics (Ta = 25°C)

$I_F = 15A$

2%

Device Schematics and Outline Drawing

Die Thickness *